TOSHIBA THYRISTOR SILICON PLANAR TYPE

# SF16GZ51,SF16JZ51

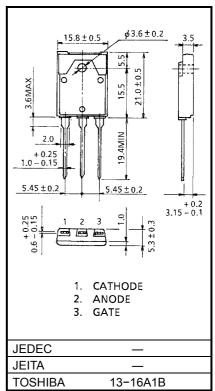
#### MEDIUM POWER CONTROL APPLICATIONS

•	Repetitive Peak Off-State Voltage:	VDRM = 400,600V
	Repetitive Peak Reverse Voltage :	$V_{\rm RRM} = 400,600 V$

- Average On–State Current : I<sub>T</sub> (AV) = 16A
- Isolation Voltage : VIsol = 1500V AC

#### **MAXIMUM RATINGS**

	CHARACTERIS	SYMBOL	MBOL RATING			
	Repetitive Peak Off-State Voltage and	SF16GZ51	V <sub>DRM</sub>	400	V	
	Repetitive Peak Reverse Voltage	SF16JZ51	V <sub>RRM</sub>	600	v	
	Non-Repetitive Peak Reverse Voltage (Non-Repetitive <5ms, $T_j = 0~125$ °C)	SF16GZ51	- V <sub>RSM</sub>	500	V	
		SF16JZ51		720		
	Average On-State Curre (Half Sine Waveform)	ent	I <sub>T(AV)</sub>	16	А	
	R.M.S On-State Current	I <sub>T(RMS)</sub>	25	А		
	Peak One Cycle Surge (	Dn-State		250 (50Hz)	А	
	Current (Non-Repetitive)		ITSM	275 (60Hz)	~	
	I <sup>2</sup> t Limit Value		l <sup>2</sup> t	312	A <sup>2</sup> s	
	Critical Rate of Rise of C Curret	di / dt	100	Α / μs		
	Peak Gate Power Dissip	P <sub>GM</sub>	5	W		
www.Datas	Average Gate Power Dis	sipation	P <sub>G (AV)</sub>	0.5	W	
	Peak Forward Gate Volta	Forward Gate Voltage		10	V	
	Peak Reverse Gate Volta	V <sub>RGM</sub>	-5	V		
	Peak Forward Gate Curr	I <sub>GM</sub>	2	A		
	Junction Temperature	Tj	-40~125	°C		
	Storage Temperature Ra	T <sub>stg</sub>	-40~125	°C		
	Isolation Voltage (AC, t =	V <sub>Isol</sub>	1500	V		



Weight: 5.9g

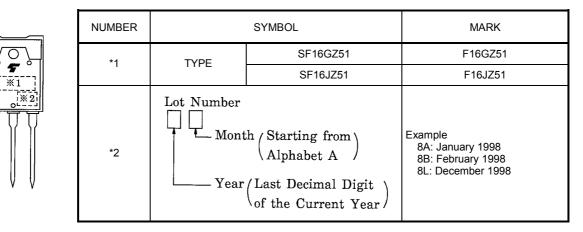
Note : di / dt Test Condition, i\_G = 30mA, t\_{gw} = 10 \mu s, t\_{gr} \le 250 n s

Unit: mm

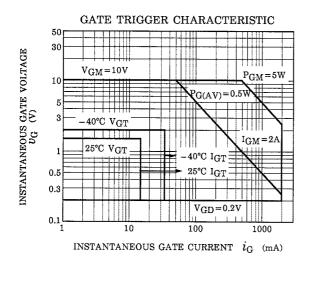
### ELECTRICAL CHARACTERISTICS (Ta = 25°C)

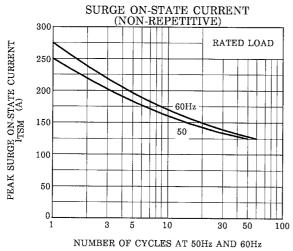
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I <sub>DRM</sub> I <sub>RRM</sub>	V <sub>DRM</sub> = V <sub>RRM</sub> = Rated	_	_	20	μA
Peak On-State Voltage	V <sub>TM</sub>	I <sub>TM</sub> = 50A	_	_	1.5	V
Gate Trigger Voltage	V <sub>GT</sub>	V <sub>D</sub> = 6V, R <sub>I</sub> = 10Ω		_	1.5	V
Gate Trigger Current	I <sub>GT</sub>	$v_{\rm D} = 0v, \kappa_{\rm L} = 1002$	_	_	15	mA
Holding Current	Ι <sub>Η</sub>	V <sub>D</sub> = 6V, I <sub>TM</sub> = 500mA	_	_	50	mA
Critical Rate of Rise of Off-State Voltage	dv / dt	V <sub>DRM</sub> = Rated, Tc = 125°C Exponential Rise	_	50	_	V / µs
Thermal Resistance	R <sub>th (j−c)</sub>	Junction to Case	-	_	1.5	°C/W

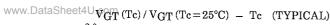
#### MARKING

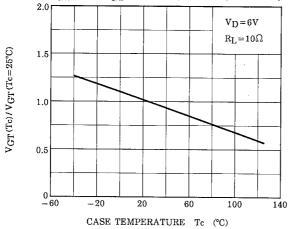


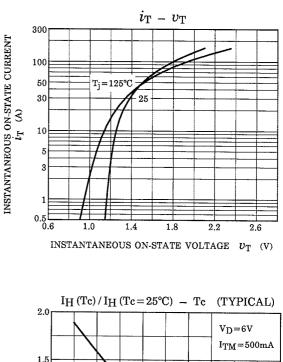
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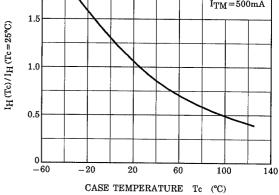


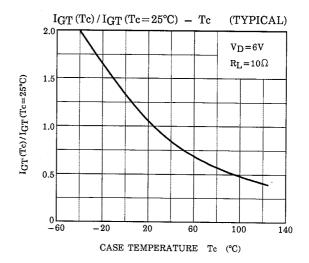




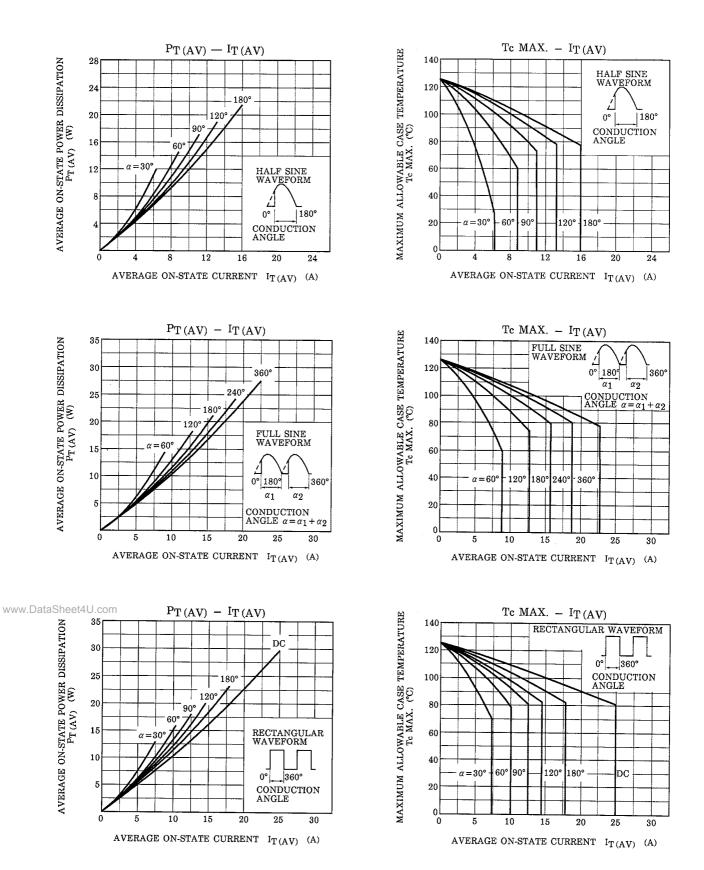




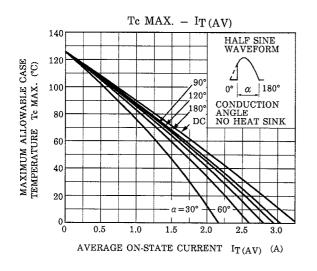


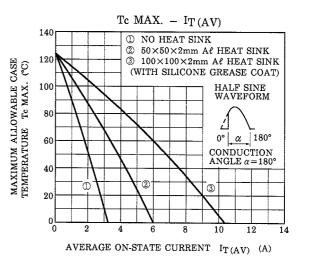


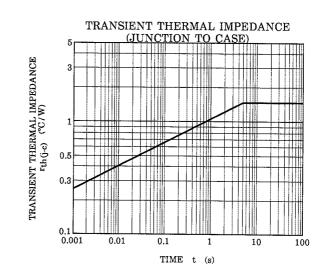
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PULSE TRIGGER CHARACTERISTIC (TYPICAL) RESISTANCE LOAD  $V_{D}=6V$   $R_{L}=10\Omega$   $T_{c}=25^{\circ}C$ RECTANGULAR WAVEFORM 3 iGT (tw)/IGT  $\downarrow^{i_{\text{GT}}}$ tw 0.51 3 5 10 30 50 300 100

GATE TRIGGER PULSE WIDTH  $t_w$  ( $\mu$ s)

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